

# SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

# CPH5504—NPN Epitaxial Planar Silicon Transistor

# **High-Current Switching Applications**

### **Applications**

· DC-DC converter, relay drivers, lamp drivers, motor drivers, flash

#### **Features**

- · Composite type with 2 NPN transistors in one package facilitating high-density mounting
- The CPH5504 is composed of 2 chips each equivaient to the CPH3205
- Ultrasmall package facilitates miniaturization in end products. (mounting height: 0.9mm)

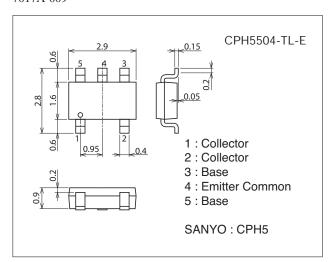
### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		100	V
Collector-to-Emitter Voltage	VCES		100	V
Collector-to-Emitter Voltage	VCEO		50	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		6	V
Collector Current	IC		3	Α
Collector Current (Pulse)	ICP		6	Α
Base Current	ΙΒ		600	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm <sup>2</sup> ×0.8mm)	0.9	W
Total Power Dissipation	PT	Mounted on a ceramic board (600mm <sup>2</sup> x0.8mm)	1.2	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### **Package Dimensions**

unit : mm (typ) 7017A-009

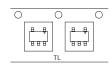


#### **Product & Package Information**

• Package : CPH5

JEITA, JEDEC : SC-74A, SOT-25
 Minimum Packing Quantity : 3,000 pcs./reel

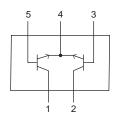
#### Packing Type : TL



# Marking



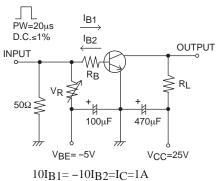
#### **Electrical Connection**



## Electrical Characteristics at Ta=25°C

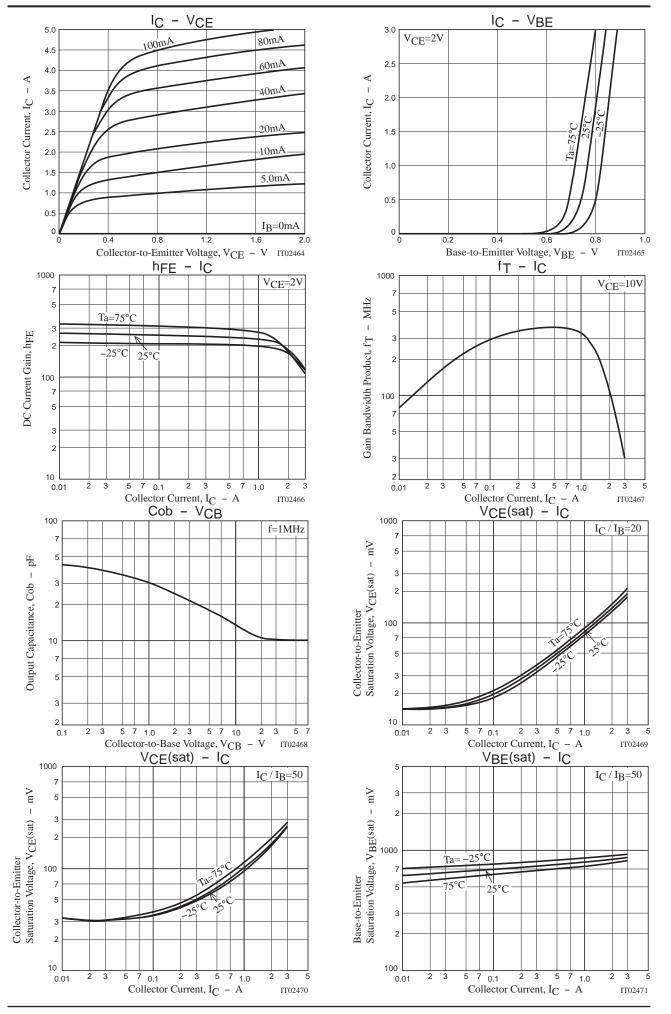
Parameter	Cumbal	Conditions	Ratings			Linit	
Parameter	Symbol	Conditions	min	typ	max	Unit	
Collector Cutoff Current	ICBO	VCB=40V, IE=0A			1	μΑ	
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =4V, I <sub>C</sub> =0A			1	μΑ	
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =2V, I <sub>C</sub> =100mA	200		560		
	h <sub>FE</sub> 2	V <sub>CE</sub> =2V, I <sub>C</sub> =3A	70				
Gain-Bandwidth Product	fŢ	VCE=10V, IC=500mA		380		MHz	
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		13		pF	
Collector to Emitter Saturation Voltage	\/ = =(oot)	I <sub>C</sub> =1A, I <sub>B</sub> =50mA		80	120	mV	
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =2A, I <sub>B</sub> =100mA		140	210	mV	
Base-to-Emitter Saturation Voltage	VBE(sat)	IC=2A, IB=100mA		0.88	1.2	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0A	100			V	
Collector-to-Base Breakdown Voltage	V(BR)CES	I <sub>C</sub> =100μA,R <sub>BE</sub> =0Ω	100			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =1mA, R <sub>BE</sub> =∞	50			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=10μA, IC=0A	6			V	
Turn-On Time	ton			35		ns	
Storage Time	tstg	See specified Test Circuit.		300		ns	
Fall Time	tf			22		ns	

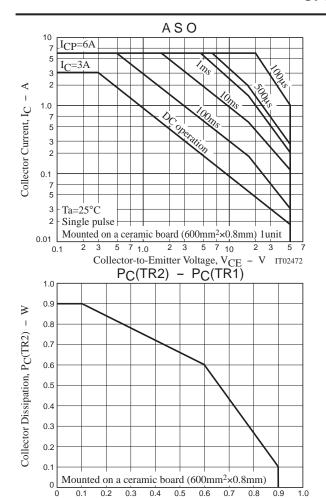
# **Switching Time Test Circuit**



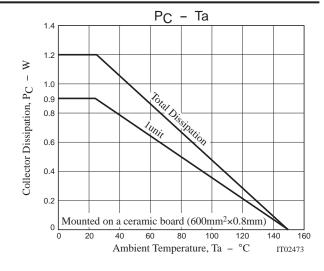
# **Ordering Information**

Device	Device Package		memo	
CPH5504-TL-E	CPH5	3,000pcs./reel	Pb Free	





Collector Dissipation,  $P_C(TR1) - W$  IT02474

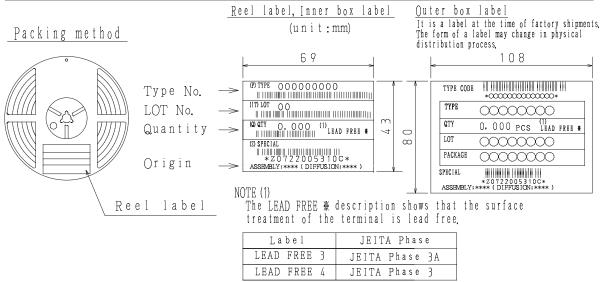


### **Embossed Taping Specification**

#### CPH5504-TL-E

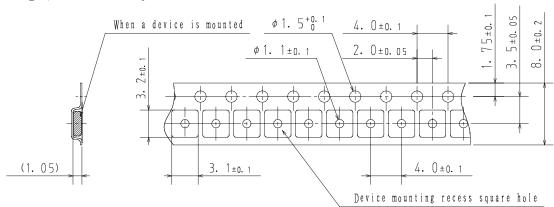
#### 1. Packing Format

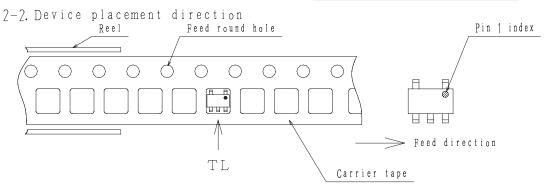
Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing	format
	Туре	Reel	Inner box	Outer box	Inner $BOX(C-1)$	Outer BOX (A-7)
CPH5	СРН6	3, 000	15, 000	90,000	5 reels contained	6 inner boxes contained
					Dimensions:mm (external)	Dimensions:mm (external)
					183×72×185	440×195×210



#### 7. Taping configuration

#### 2-1. Carrier tape size (unit:mm)

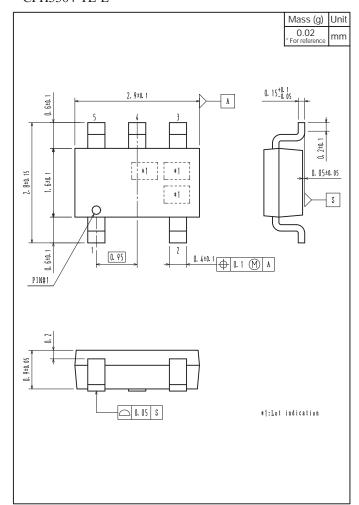




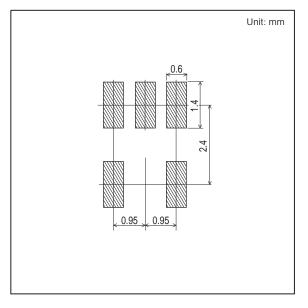
Those with pin 1 index on the feed hole side · · · · · TL

# Outline Drawing

## CPH5504-TL-E



# Land Pattern Example



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